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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	e200z0h
Core Size	32-Bit Single-Core
Speed	64MHz
Connectivity	CANbus, I <sup>2</sup> C, LINbus, SCI, SPI
Peripherals	DMA, POR, PWM, WDT
Number of I/O	79
Program Memory Size	512KB (512K x 8)
Program Memory Type	FLASH
EEPROM Size	64K x 8
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	A/D 28x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/nxp-semiconductors/spc5604bk0vll6r">https://www.e-xfl.com/product-detail/nxp-semiconductors/spc5604bk0vll6r</a>

Table 2. MPC5604B/C device comparison<sup>1</sup>

Feature	Device										
	SPC560B 40L1	SPC560B 40L3	SPC560B 40L5	SPC560C 40L1	SPC560C 40L3	SPC560B 50L1	SPC560B 50L3	SPC560B 50L5	SPC560C 50L1	SPC560C 50L3	SPC560B 50B2
CPU	e200z0h										
Execution speed <sup>2</sup>	Static – up to 64 MHz										
Code Flash	256 KB					512 KB					
Data Flash	64 KB (4 × 16 KB)										
RAM	24 KB			32 KB		32 KB			48 KB		
MPU	8-entry										
ADC (10-bit)	12 ch	28 ch	36 ch	8 ch	28 ch	12 ch	28 ch	36 ch	8 ch	28 ch	36 ch
CTU	Yes										
Total timer I/O <sup>3</sup>	12 ch, 16-bit	28 ch, 16-bit	56 ch, 16-bit	12 ch, 16-bit	28 ch, 16-bit	12 ch, 16-bit	28 ch, 16-bit	56 ch, 16-bit	12 ch, 16-bit	28 ch, 16-bit	56 ch, 16-bit
eMIOS											
• PWM + MC + IC/OC <sup>4</sup>	2 ch	5 ch	10 ch	2 ch	5 ch	2 ch	5 ch	10 ch	2 ch	5 ch	10 ch
• PWM + IC/OC <sup>4</sup>	10 ch	20 ch	40 ch	10 ch	20 ch	10 ch	20 ch	40 ch	10 ch	20 ch	40 ch
• IC/OC <sup>4</sup>	—	3 ch	6 ch	—	3 ch	—	3 ch	6 ch	—	3 ch	6 ch
SCI (LINFlex)	3 <sup>5</sup>			4							
SPI (DSPI)	2	3		2	3	2	3		2	3	
CAN (FlexCAN)	2 <sup>6</sup>			5	6	3 <sup>7</sup>			5	6	
I <sup>2</sup> C	1										
32 kHz oscillator	Yes										
GPIO <sup>8</sup>	45	79	123	45	79	45	79	123	45	79	123
Debug	JTAG										Nexus2+
Package	LQFP64 <sup>9</sup>	LQFP100	LQFP144	LQFP64 <sup>9</sup>	LQFP100	LQFP64 <sup>9</sup>	LQFP100	LQFP144	LQFP64 <sup>9</sup>	LQFP100	LBGA208 <sup>10</sup>

<sup>1</sup> Feature set dependent on selected peripheral multiplexing—table shows example implementation

<sup>2</sup> Based on 125 °C ambient operating temperature

<sup>3</sup> See the eMIOS section of the device reference manual for information on the channel configuration and functions.

<sup>4</sup> IC – Input Capture; OC – Output Compare; PWM – Pulse Width Modulation; MC – Modulus counter

<sup>5</sup> SCI0, SCI1 and SCI2 are available. SCI3 is not available.

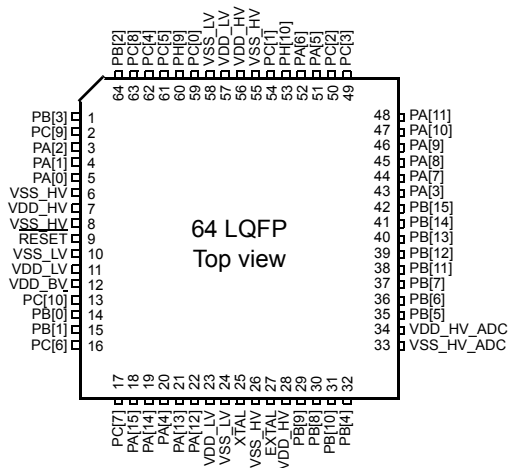


Figure 2. MPC560xB LQFP 64-pin configuration

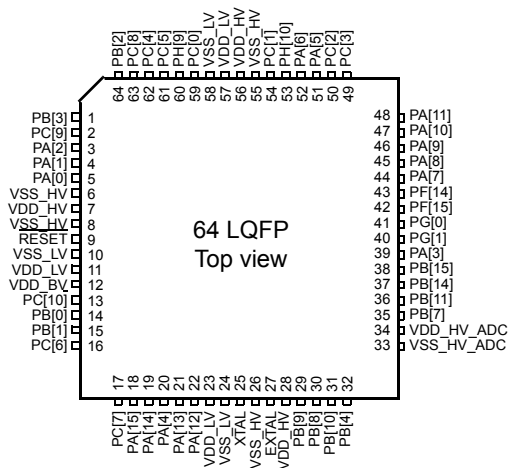
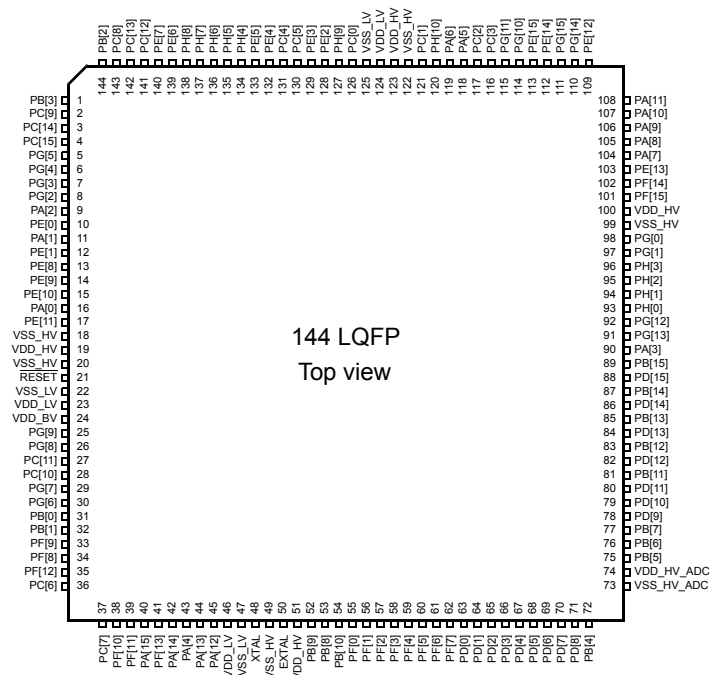


Figure 3. MPC560xC LQFP 64-pin configuration



Note:

Availability of port pin alternate functions depends on product selection.

Figure 5. LQFP 144-pin configuration

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA <sup>3</sup>
PD[1]	PCR[49]	AF0 AF1 AF2 AF3 —	GPIO[49] — — — GPIO[5]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	42	64	T12
PD[2]	PCR[50]	AF0 AF1 AF2 AF3 —	GPIO[50] — — — GPIO[6]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	43	65	R12
PD[3]	PCR[51]	AF0 AF1 AF2 AF3 —	GPIO[51] — — — GPIO[7]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	44	66	P13
PD[4]	PCR[52]	AF0 AF1 AF2 AF3 —	GPIO[52] — — — GPIO[8]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	45	67	R13
PD[5]	PCR[53]	AF0 AF1 AF2 AF3 —	GPIO[53] — — — GPIO[9]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	46	68	T13
PD[6]	PCR[54]	AF0 AF1 AF2 AF3 —	GPIO[54] — — — GPIO[10]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	47	69	T14
PD[7]	PCR[55]	AF0 AF1 AF2 AF3 —	GPIO[55] — — — GPIO[11]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	48	70	R14
PD[8]	PCR[56]	AF0 AF1 AF2 AF3 —	GPIO[56] — — — GPIO[12]	SIUL — — — ADC	I — — — I	I	Tristate	—	—	49	71	T15

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA <sup>3</sup>
PF[2]	PCR[82]	AF0 AF1 AF2 AF3 —	GPIO[82] E0UC[12] CS0_2 — ANS[10]	SIUL eMIOS_0 DSPI_2 — ADC	I/O I/O I/O — I	J	Tristate	—	—	—	57	T10
PF[3]	PCR[83]	AF0 AF1 AF2 AF3 —	GPIO[83] E0UC[13] CS1_2 — ANS[11]	SIUL eMIOS_0 DSPI_2 — ADC	I/O I/O O — I	J	Tristate	—	—	—	58	R10
PF[4]	PCR[84]	AF0 AF1 AF2 AF3 —	GPIO[84] E0UC[14] CS2_2 — ANS[12]	SIUL eMIOS_0 DSPI_2 — ADC	I/O I/O O — I	J	Tristate	—	—	—	59	N11
PF[5]	PCR[85]	AF0 AF1 AF2 AF3 —	GPIO[85] E0UC[22] CS3_2 — ANS[13]	SIUL eMIOS_0 DSPI_2 — ADC	I/O I/O O — I	J	Tristate	—	—	—	60	P11
PF[6]	PCR[86]	AF0 AF1 AF2 AF3 —	GPIO[86] E0UC[23] — — ANS[14]	SIUL eMIOS_0 — — ADC	I/O I/O — — I	J	Tristate	—	—	—	61	T11
PF[7]	PCR[87]	AF0 AF1 AF2 AF3 —	GPIO[87] — — — ANS[15]	SIUL — — — ADC	I/O — — — I	J	Tristate	—	—	—	62	R11
PF[8]	PCR[88]	AF0 AF1 AF2 AF3	GPIO[88] CAN3TX <sup>14</sup> CS4_0 CAN2TX <sup>15</sup>	SIUL FlexCAN_3 DSPI_0 FlexCAN_2	I/O O O O	M	Tristate	—	—	—	34	P1
PF[9]	PCR[89]	AF0 AF1 AF2 AF3 — —	GPIO[89] — CS5_0 — CAN2RX <sup>15</sup> CAN3RX <sup>14</sup>	SIUL — DSPI_0 — FlexCAN_2 FlexCAN_3	I/O — O — I I	S	Tristate	—	—	—	33	N2

Table 6. Functional port pin descriptions (continued)

Port pin	PCR	Alternate function <sup>1</sup>	Function	Peripheral	I/O direction <sup>2</sup>	Pad type	RESET configuration	Pin number				
								MPC560xB 64 LQFP	MPC560xC 64 LQFP	100 LQFP	144 LQFP	208 MAPBGA <sup>3</sup>
PH[4]	PCR[116]	AF0 AF1 AF2 AF3	GPIO[116] E1UC[6] — —	SIUL eMIOS_1 — —	I/O I/O — —	M	Tristate	—	—	—	134	A6
PH[5]	PCR[117]	AF0 AF1 AF2 AF3	GPIO[117] E1UC[7] — —	SIUL eMIOS_1 — —	I/O I/O — —	S	Tristate	—	—	—	135	B6
PH[6]	PCR[118]	AF0 AF1 AF2 AF3	GPIO[118] E1UC[8] — MA[2]	SIUL eMIOS_1 — ADC	I/O I/O — O	M	Tristate	—	—	—	136	D5
PH[7]	PCR[119]	AF0 AF1 AF2 AF3	GPIO[119] E1UC[9] CS3_2 MA[1]	SIUL eMIOS_1 DSPI_2 ADC	I/O I/O O O	M	Tristate	—	—	—	137	C5
PH[8]	PCR[120]	AF0 AF1 AF2 AF3	GPIO[120] E1UC[10] CS2_2 MA[0]	SIUL eMIOS_1 DSPI_2 ADC	I/O I/O O O	M	Tristate	—	—	—	138	A5
PH[9] <sup>9</sup>	PCR[121]	AF0 AF1 AF2 AF3	GPIO[121] — TCK —	SIUL — JTAGC —	I/O — I —	S	Input, weak pull-up	60	60	88	127	B8
PH[10] <sup>9</sup>	PCR[122]	AF0 AF1 AF2 AF3	GPIO[122] — TMS —	SIUL — JTAGC —	I/O — I —	S	Input, weak pull-up	53	53	81	120	B9

<sup>1</sup> Alternate functions are chosen by setting the values of the PCR.PA bitfields inside the SIUL module.  
PCR.PA = 00 → AF0; PCR.PA = 01 → AF1; PCR.PA = 10 → AF2; PCR.PA = 11 → AF3. This is intended to select the output functions; to use one of the input functions, the PCR.IBE bit must be written to '1', regardless of the values selected in the PCR.PA bitfields. For this reason, the value corresponding to an input only function is reported as "—".

<sup>2</sup> Multiple inputs are routed to all respective modules internally. The input of some modules must be configured by setting the values of the PSMIO.PADSELx bitfields inside the SIUL module.

<sup>3</sup> 208 MAPBGA available only as development package for Nexus2+

<sup>4</sup> All WKPU pins also support external interrupt capability. See wakeup unit chapter for further details.

<sup>5</sup> NMI has higher priority than alternate function. When NMI is selected, the PCR.AF field is ignored.

<sup>6</sup> "Not applicable" because these functions are available only while the device is booting. Refer to BAM chapter of the reference manual for details.

<sup>1</sup> Default manufacturing value is '1'. Value can be programmed by customer in Shadow Flash.

### 3.11.2 NVUSRO[OSCILLATOR\_MARGIN] field description

The fast external crystal oscillator consumption is dependent on the OSCILLATOR\_MARGIN bit value. [Table 10](#) shows how NVUSRO[OSCILLATOR\_MARGIN] controls the device configuration.

**Table 10. OSCILLATOR\_MARGIN field description**

Value <sup>1</sup>	Description
0	Low consumption configuration (4 MHz/8 MHz)
1	High margin configuration (4 MHz/16 MHz)

<sup>1</sup> Default manufacturing value is '1'. Value can be programmed by customer in Shadow Flash.

### 3.11.3 NVUSRO[WATCHDOG\_EN] field description

The watchdog enable/disable configuration after reset is dependent on the WATCHDOG\_EN bit value. [Table 11](#) shows how NVUSRO[WATCHDOG\_EN] controls the device configuration.

**Table 11. WATCHDOG\_EN field description**

Value <sup>1</sup>	Description
0	Disable after reset
1	Enable after reset

<sup>1</sup> Default manufacturing value is '1'. Value can be programmed by customer in Shadow Flash.



<sup>2</sup>  $C_L$  includes device and package capacitances ( $C_{PKG} < 5$  pF).

### 3.15.5 I/O pad current specification

The I/O pads are distributed across the I/O supply segment. Each I/O supply segment is associated to a  $V_{DD}/V_{SS}$  supply pair as described in [Table 22](#).

**Table 22. I/O supply segment**

Package	Supply segment					
	1	2	3	4	5	6
208 MAPBGA <sup>1</sup>	Equivalent to 144 LQFP segment pad distribution				MCKO	MDO <sub>n</sub> /MSEO
144 LQFP	pin20–pin49	pin51–pin99	pin100–pin122	pin 123–pin19	—	—
100 LQFP	pin16–pin35	pin37–pin69	pin70–pin83	pin 84–pin15	—	—
64 LQFP	pin8–pin26	pin28–pin55	pin56–pin7	—	—	—

<sup>1</sup> 208 MAPBGA available only as development package for Nexus2+

[Table 23](#) provides I/O consumption figures.

In order to ensure device reliability, the average current of the I/O on a single segment should remain below the  $I_{AVGSEG}$  maximum value.

**Table 23. I/O consumption**

Symbol	C		Parameter	Conditions <sup>1</sup>		Value			Unit
						Min	Typ	Max	
I <sub>SWTSLW</sub> <sup>2</sup>	CC	D	Dynamic I/O current for SLOW configuration	C <sub>L</sub> = 25 pF	V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 0	—	—	20	mA
					V <sub>DD</sub> = 3.3 V ± 10%, PAD3V5V = 1	—	—	16	
I <sub>SWTMED</sub> <sup>2</sup>	CC	D	Dynamic I/O current for MEDIUM configuration	C <sub>L</sub> = 25 pF	V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 0	—	—	29	mA
					V <sub>DD</sub> = 3.3 V ± 10%, PAD3V5V = 1	—	—	17	
I <sub>SWTFST</sub> <sup>2</sup>	CC	D	Dynamic I/O current for FAST configuration	C <sub>L</sub> = 25 pF	V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 0	—	—	110	mA
					V <sub>DD</sub> = 3.3 V ± 10%, PAD3V5V = 1	—	—	50	
I <sub>RMSSLW</sub>	CC	D	Root mean square I/O current for SLOW configuration	C <sub>L</sub> = 25 pF, 2 MHz	V <sub>DD</sub> = 5.0 V ± 10%, PAD3V5V = 0	—	—	2.3	mA
				C <sub>L</sub> = 25 pF, 4 MHz		—	—	3.2	
				C <sub>L</sub> = 100 pF, 2 MHz		—	—	6.6	
				C <sub>L</sub> = 25 pF, 2 MHz	V <sub>DD</sub> = 3.3 V ± 10%, PAD3V5V = 1	—	—	1.6	
				C <sub>L</sub> = 25 pF, 4 MHz		—	—	2.3	
				C <sub>L</sub> = 100 pF, 2 MHz		—	—	4.7	

Table 24. I/O weight<sup>1</sup> (continued)

Supply segment			Pad	144/100 LQFP				64 LQFP			
				Weight 5 V		Weight 3.3 V		Weight 5 V		Weight 3.3 V	
144 LQFP	100 LQFP	64 LQFP <sup>2</sup>		SRC <sup>3</sup> = 0	SRC = 1	SRC = 0	SRC = 1	SRC = 0	SRC = 1	SRC = 0	SRC = 1
4	—	—	PG[2]	8%	12%	10%	10%	—	—	—	—
	4	3	PA[2]	8%	—	9%	—	8%	—	9%	—
		—	PE[0]	8%	—	9%	—	—	—	—	—
		3	PA[1]	7%	—	9%	—	7%	—	9%	—
		—	PE[1]	7%	10%	8%	9%	—	—	—	—
		—	PE[8]	7%	9%	8%	8%	—	—	—	—
		—	PE[9]	6%	—	7%	—	—	—	—	—
		—	PE[10]	6%	—	7%	—	—	—	—	—
		3	PA[0]	5%	8%	6%	7%	5%	8%	6%	7%
		—	PE[11]	5%	—	6%	—	—	—	—	—
1	—	—	PG[9]	9%	—	10%	—	—	—	—	—
	—	—	PG[8]	9%	—	11%	—	—	—	—	—
	1	—	PC[11]	9%	—	11%	—	—	—	—	—
		1	PC[10]	9%	13%	11%	12%	9%	13%	11%	12%
	—	—	PG[7]	10%	14%	11%	12%	—	—	—	—
	—	—	PG[6]	10%	14%	12%	12%	—	—	—	—
	1	1	PB[0]	10%	14%	12%	12%	10%	14%	12%	12%
			PB[1]	10%	—	12%	—	10%	—	12%	—
	—	—	PF[9]	10%	—	12%	—	—	—	—	—
	—	—	PF[8]	10%	15%	12%	13%	—	—	—	—
	—	—	PF[12]	10%	15%	12%	13%	—	—	—	—
	1	1	PC[6]	10%	—	12%	—	10%	—	12%	—
			PC[7]	10%	—	12%	—	10%	—	12%	—
	—	—	PF[10]	10%	14%	12%	12%	—	—	—	—
	—	—	PF[11]	10%	—	11%	—	—	—	—	—
	1	1	PA[15]	9%	12%	10%	11%	9%	12%	10%	11%
	—	—	PF[13]	8%	—	10%	—	—	—	—	—
	1	1	PA[14]	8%	11%	9%	10%	8%	11%	9%	10%
			PA[4]	8%	—	9%	—	8%	—	9%	—
			PA[13]	7%	10%	9%	9%	7%	10%	9%	9%
			PA[12]	7%	—	8%	—	7%	—	8%	—

**Example 1. No regulator (worst case)**

The  $|\Delta V_{DD}(STDBY)|$  parameter can be seen as the  $V_{DD}$  voltage drop through the ESR resistance of the regulator stability capacitor when the  $I_{DD\_BV}$  current required to load  $V_{DD\_LV}$  domain during the standby exit. It is thus possible to define the maximum equivalent resistance  $ESR_{STDBY}(MAX)$  of the total capacitance on the  $V_{DD}$  supply:

$$ESR_{STDBY}(MAX) = |\Delta V_{DD}(STDBY)| / I_{DD\_BV} = (30 \text{ mV}) / (300 \text{ mA}) = 0.1 \Omega^1$$

The  $dV_{DD}(STDBY)/dt$  parameter can be seen as the  $V_{DD}$  voltage drop at the capacitance pin (excluding ESR drop) while providing the  $I_{DD\_BV}$  supply required to load  $V_{DD\_LV}$  domain during the standby exit. It is thus possible to define the minimum equivalent capacitance  $C_{STDBY}(MIN)$  of the total capacitance on the  $V_{DD}$  supply:

$$C_{STDBY}(MIN) = I_{DD\_BV} / dV_{DD}(STDBY)/dt = (300 \text{ mA}) / (15 \text{ mV}/\mu\text{s}) = 20 \mu\text{F}$$

This configuration is a worst case, with the assumption no regulator is available.

**Example 2. Simplified regulator**

The regulator should be able to provide significant amount of the current during the standby exit process. For example, in case of an ideal voltage regulator providing 200 mA current, it is possible to recalculate the equivalent  $ESR_{STDBY}(MAX)$  and  $C_{STDBY}(MIN)$  as follows:

$$ESR_{STDBY}(MAX) = |\Delta V_{DD}(STDBY)| / (I_{DD\_BV} - 200 \text{ mA}) = (30 \text{ mV}) / (100 \text{ mA}) = 0.3 \Omega$$

$$C_{STDBY}(MIN) = (I_{DD\_BV} - 200 \text{ mA}) / dV_{DD}(STDBY)/dt = (300 \text{ mA} - 200 \text{ mA}) / (15 \text{ mV}/\mu\text{s}) = 6.7 \mu\text{F}$$

In case optimization is required,  $C_{STDBY}(MIN)$  and  $ESR_{STDBY}(MAX)$  should be calculated based on the regulator characteristics as well as the board  $V_{DD}$  plane characteristics.

**3.17.2 Low voltage detector electrical characteristics**

The device implements a Power-on Reset (POR) module to ensure correct power-up initialization, as well as four low voltage detectors (LVDs) to monitor the  $V_{DD}$  and the  $V_{DD\_LV}$  voltage while device is supplied:

- POR monitors  $V_{DD}$  during the power-up phase to ensure device is maintained in a safe reset state (refer to RGM Destructive Event Status (RGM\_DES) Register flag F\_POR in device reference manual)
- LVDHV3 monitors  $V_{DD}$  to ensure device reset below minimum functional supply (refer to RGM Destructive Event Status (RGM\_DES) Register flag F\_LVD27 in device reference manual)
- LVDHV5 monitors  $V_{DD}$  when application uses device in the  $5.0 \text{ V} \pm 10\%$  range (refer to RGM Functional Event Status (RGM\_FES) Register flag F\_LVD45 in device reference manual)
- LVDLVCOR monitors power domain No. 1 (refer to RGM Destructive Event Status (RGM\_DES) Register flag F\_LVD12\_PD1 in device reference manual)
- LVDLVBKP monitors power domain No. 0 (refer to RGM Destructive Event Status (RGM\_DES) Register flag F\_LVD12\_PD0 in device reference manual)

**NOTE**

When enabled, power domain No. 2 is monitored through LVDLVBKP.

1. Based on typical time for standby exit sequence of 20  $\mu\text{s}$ ,  $ESR(MIN)$  can actually be considered at  $\sim 50 \text{ kHz}$ .

Table 28. Power consumption on VDD\_BV and VDD\_HV

Symbol		C	Parameter	Conditions <sup>1</sup>		Value			Unit
						Min	Typ	Max	
I <sub>DDMAX</sub> <sup>2</sup>	CC	D	RUN mode maximum average current	—		—	115	140 <sup>3</sup>	mA
I <sub>DDRUN</sub> <sup>4</sup>	CC	T	RUN mode typical average current <sup>5</sup>	f <sub>CPU</sub> = 8 MHz	—	7	—	mA	
		T		f <sub>CPU</sub> = 16 MHz	—	18	—		
		T		f <sub>CPU</sub> = 32 MHz	—	29	—		
		P		f <sub>CPU</sub> = 48 MHz	—	40	100		
		P		f <sub>CPU</sub> = 64 MHz	—	51	125		
I <sub>DDHALT</sub>	CC	C	HALT mode current <sup>6</sup>	Slow internal RC oscillator (128 kHz) running	T <sub>A</sub> = 25 °C	—	8	15	mA
		P			T <sub>A</sub> = 125 °C	—	14	25	
I <sub>DDSTOP</sub>	CC	P	STOP mode current <sup>7</sup>	Slow internal RC oscillator (128 kHz) running	T <sub>A</sub> = 25 °C	—	180	700 <sup>8</sup>	μA
		D			T <sub>A</sub> = 55 °C	—	500	—	
		D			T <sub>A</sub> = 85 °C	—	1	6 <sup>8</sup>	mA
		D			T <sub>A</sub> = 105 °C	—	2	9 <sup>8</sup>	
		P			T <sub>A</sub> = 125 °C	—	4.5	12 <sup>8</sup>	
I <sub>DDSTDBY2</sub>	CC	P	STANDBY2 mode current <sup>9</sup>	Slow internal RC oscillator (128 kHz) running	T <sub>A</sub> = 25 °C	—	30	100	μA
		D			T <sub>A</sub> = 55 °C	—	75	—	
		D			T <sub>A</sub> = 85 °C	—	180	700	
		D			T <sub>A</sub> = 105 °C	—	315	1000	
		P			T <sub>A</sub> = 125 °C	—	560	1700	
I <sub>DDSTDBY1</sub>	CC	T	STANDBY1 mode current <sup>10</sup>	Slow internal RC oscillator (128 kHz) running	T <sub>A</sub> = 25 °C	—	20	60	μA
		D			T <sub>A</sub> = 55 °C	—	45	—	
		D			T <sub>A</sub> = 85 °C	—	100	350	
		D			T <sub>A</sub> = 105 °C	—	165	500	
		D			T <sub>A</sub> = 125 °C	—	280	900	

<sup>1</sup>  $V_{DD} = 3.3 \text{ V} \pm 10\% / 5.0 \text{ V} \pm 10\%$ ,  $T_A = -40$  to  $125 \text{ }^\circ\text{C}$ , unless otherwise specified

<sup>2</sup>  $I_{DDMAX}$  is drawn only from the  $V_{DD\_BV}$  pin. Running consumption does not include I/Os toggling which is highly dependent on the application. The given value is thought to be a worst case value with all peripherals running, and code fetched from code flash while modify operation ongoing on data flash. Notice that this value can be significantly reduced by application: switch off not used peripherals (default), reduce peripheral frequency through internal prescaler, fetch from RAM most used functions, use low power mode when possible.

<sup>3</sup> Higher current may be sunk by device during power-up and standby exit. Please refer to inrush current on [Table 26](#).

<sup>4</sup>  $I_{DDRUN}$  is drawn only from the  $V_{DD\_BV}$  pin. RUN current measured with typical application with accesses on both flash and RAM.

<sup>5</sup> Only for the "P" classification: Data and Code Flash in Normal Power. Code fetched from RAM: Serial IPs CAN and LIN in loop back mode, DSPI as Master, PLL as system Clock (4 x Multiplier) peripherals on (eMIOS/CTU/ADC) and running at max frequency, periodic SW/WDG timer reset enabled.

**Table 42. Fast internal RC oscillator (16 MHz) electrical characteristics (continued)**

Symbol		C	Parameter	Conditions <sup>1</sup>		Value			Unit
						Min	Typ	Max	
I <sub>FIRCSTOP</sub>	CC	T	Fast internal RC oscillator high frequency and system clock current in stop mode	T <sub>A</sub> = 25 °C	sysclk = off	—	500	—	μA
					sysclk = 2 MHz	—	600	—	
					sysclk = 4 MHz	—	700	—	
					sysclk = 8 MHz	—	900	—	
					sysclk = 16 MHz	—	1250	—	
t <sub>FIRCSU</sub>	CC	C	Fast internal RC oscillator start-up time	V <sub>DD</sub> = 5.0 V ± 10%		—	1.1	2.0	μs
Δ <sub>FIRCPRE</sub>	CC	T	Fast internal RC oscillator precision after software trimming of f <sub>FIRC</sub>	T <sub>A</sub> = 25 °C		–1	—	+1	%
Δ <sub>FIRCTRM</sub>	CC	T	Fast internal RC oscillator trimming step	T <sub>A</sub> = 25 °C		—	1.6		%
Δ <sub>FIRCVAR</sub>	CC	P	Fast internal RC oscillator variation in overtemperature and supply with respect to f <sub>FIRC</sub> at T <sub>A</sub> = 25 °C in high-frequency configuration	—		–5	—	+5	%

<sup>1</sup> V<sub>DD</sub> = 3.3 V ± 10% / 5.0 V ± 10%, T<sub>A</sub> = –40 to 125 °C, unless otherwise specified.

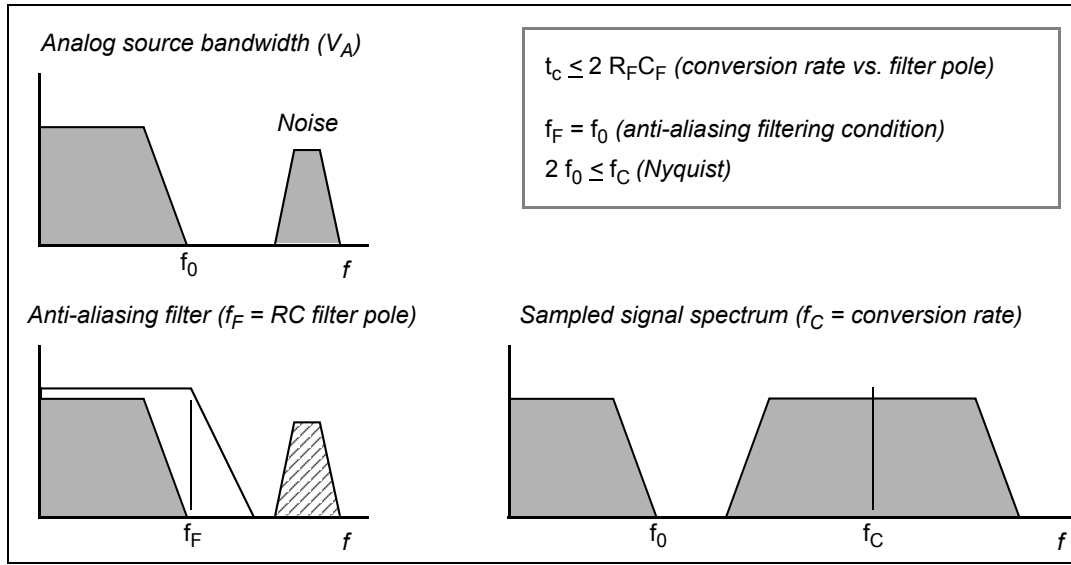
<sup>2</sup> This does not include consumption linked to clock tree toggling and peripherals consumption when RC oscillator is ON.

### 3.25 Slow internal RC oscillator (128 kHz) electrical characteristics

The device provides a 128 kHz slow internal RC oscillator. This can be used as the reference clock for the RTC module.

**Table 43. Slow internal RC oscillator (128 kHz) electrical characteristics**

Symbol		C	Parameter	Conditions <sup>1</sup>	Value			Unit
					Min	Typ	Max	
f <sub>SIRC</sub>	CC	P	Slow internal RC oscillator low frequency	T <sub>A</sub> = 25 °C, trimmed	—	128	—	kHz
	SR	—		100	—	150		
I <sub>SIRC</sub> <sup>2</sup>	CC	C	Slow internal RC oscillator low frequency current	T <sub>A</sub> = 25 °C, trimmed	—	—	5	μA
t <sub>SIRCSU</sub>	CC	P	Slow internal RC oscillator start-up time	T <sub>A</sub> = 25 °C, V <sub>DD</sub> = 5.0 V ± 10%	—	8	12	μs
Δ <sub>SIRCPRE</sub>	CC	C	Slow internal RC oscillator precision after software trimming of f <sub>SIRC</sub>	T <sub>A</sub> = 25 °C	–2	—	+2	%
Δ <sub>SIRCTRM</sub>	CC	C	Slow internal RC oscillator trimming step	—	—	2.7	—	
Δ <sub>SIRCVAR</sub>	CC	C	Slow internal RC oscillator variation in temperature and supply with respect to f <sub>SIRC</sub> at T <sub>A</sub> = 55 °C in high frequency configuration	High frequency configuration	–10	—	+10	%



**Figure 23. Spectral representation of input signal**

Calling  $f_0$  the bandwidth of the source signal (and as a consequence the cut-off frequency of the anti-aliasing filter,  $f_F$ ), according to the Nyquist theorem the conversion rate  $f_C$  must be at least  $2f_0$ ; it means that the constant time of the filter is greater than or at least equal to twice the conversion period ( $t_c$ ). Again the conversion period  $t_c$  is longer than the sampling time  $t_s$ , which is just a portion of it, even when fixed channel continuous conversion mode is selected (fastest conversion rate at a specific channel): in conclusion it is evident that the time constant of the filter  $R_F C_F$  is definitively much higher than the sampling time  $t_s$ , so the charge level on  $C_S$  cannot be modified by the analog signal source during the time in which the sampling switch is closed.

The considerations above lead to impose new constraints on the external circuit, to reduce the accuracy error due to the voltage drop on  $C_S$ ; from the two charge balance equations above, it is simple to derive Equation 11 between the ideal and real sampled voltage on  $C_S$ :

**Eqn. 11**

$$\frac{V_{A2}}{V_A} = \frac{C_{P1} + C_{P2} + C_F}{C_{P1} + C_{P2} + C_F + C_S}$$

From this formula, in the worst case (when  $V_A$  is maximum, that is for instance 5 V), assuming to accept a maximum error of half a count, a constraint is evident on  $C_F$  value:

**Eqn. 12**

$$C_F > 2048 \cdot C_S$$

## 4.1.2 100 LQFP

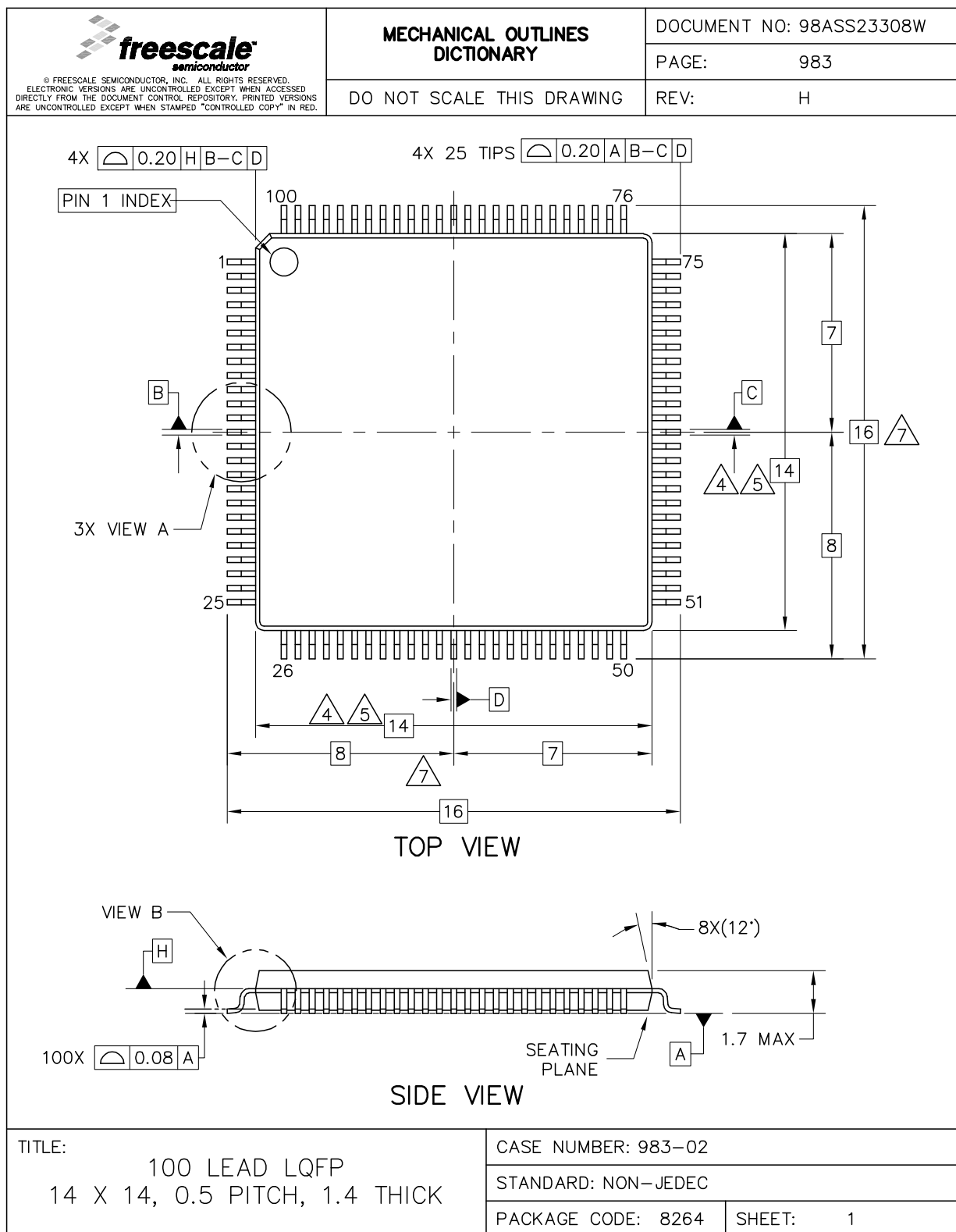


Figure 38. 100 LQFP package mechanical drawing (1 of 3)

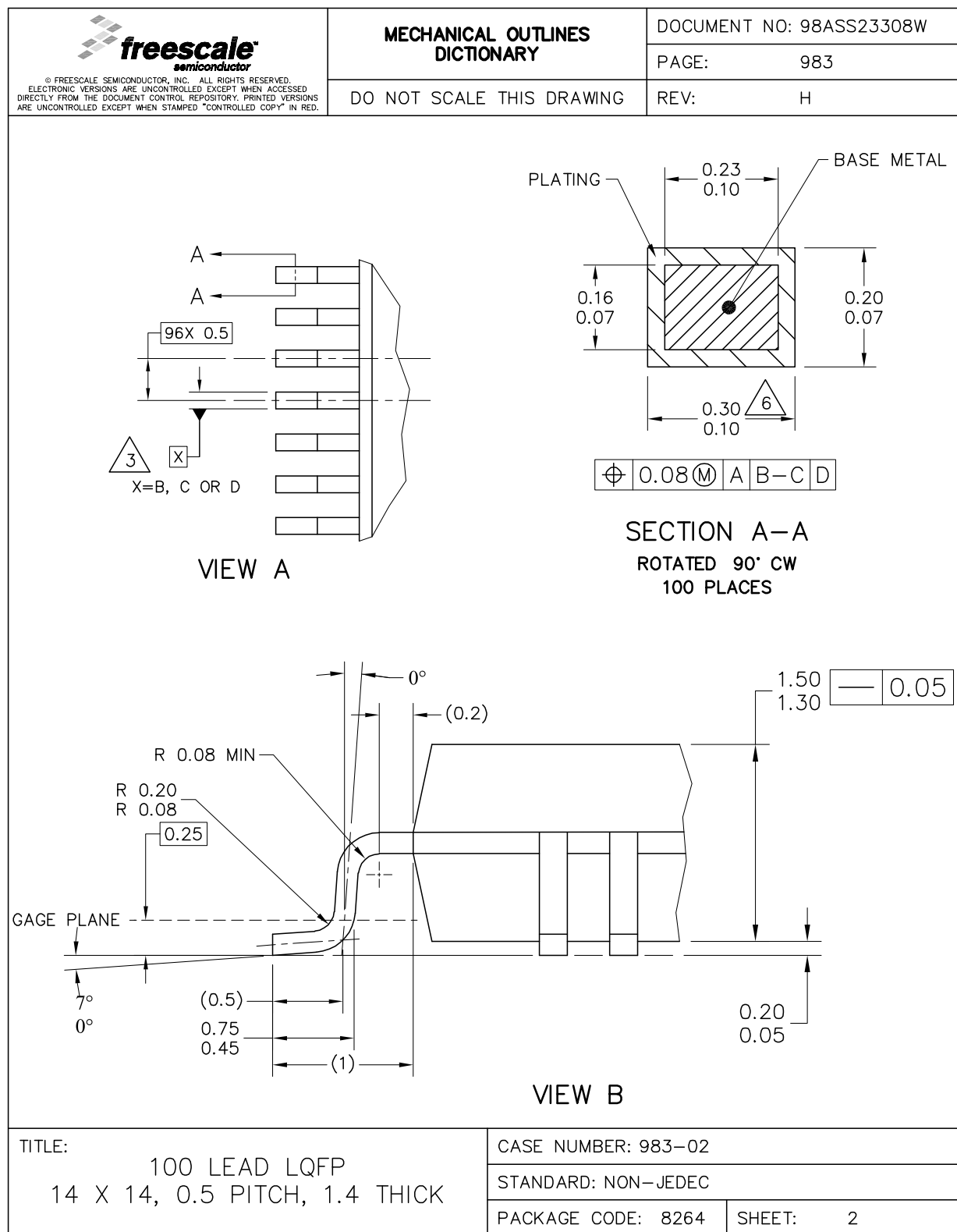


Figure 39. 100 LQFP package mechanical drawing (2 of 3)




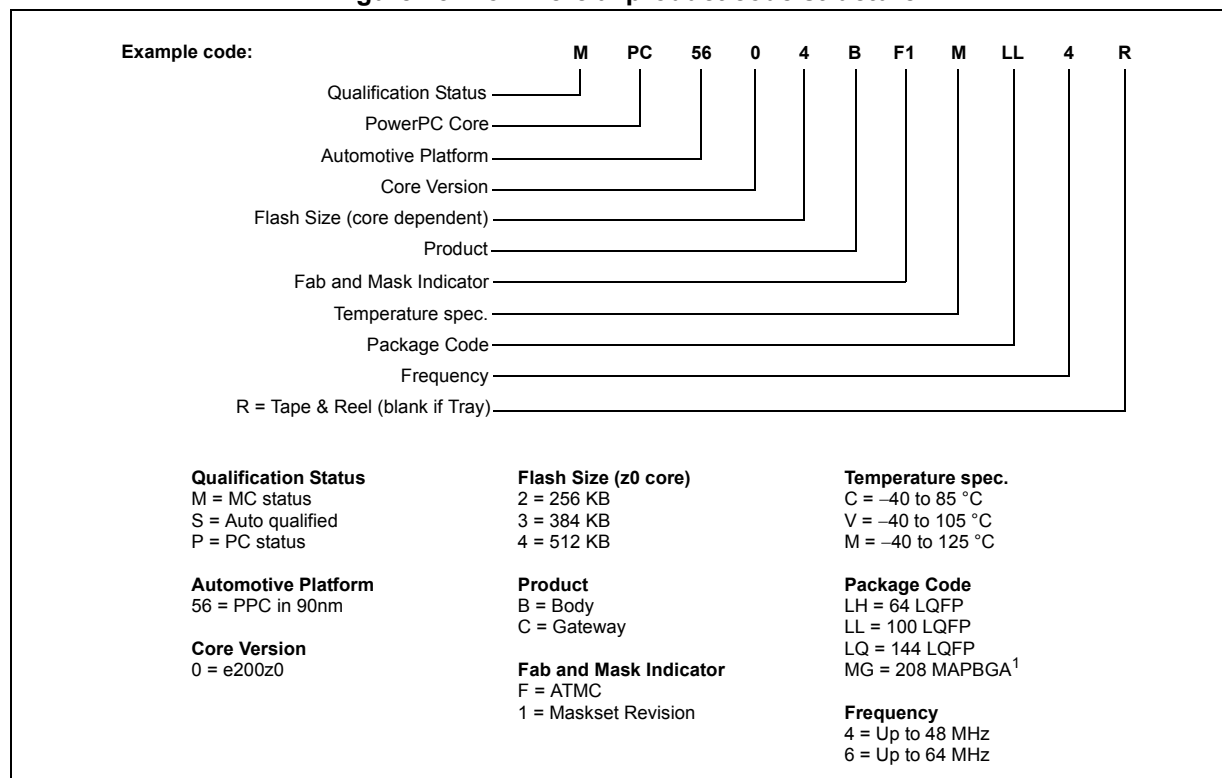
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	DO NOT SCALE THIS DRAWING		PAGE:	983
			REV:	H
<div>NOTES:</div> <div><div>1. ALL DIMENSIONS ARE IN MILLIMETERS.</div><div>2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M–1994.</div><div>3. DATUMS B, C AND D TO BE DETERMINED AT DATUM PLANE H.</div><div>4. THE TOP PACKAGE BODY SIZE MAY BE SMALLER THAN THE BOTTOM PACKAGE SIZE BY A MAXIMUM OF 0.1 MM.</div><div>5. DIMENSIONS DO NOT INCLUDE MOLD PROTRUSIONS. THE MAXIMUM ALLOWABLE PROTRUSION IS 0.25 mm PER SIDE. THE DIMENSIONS ARE MAXIMUM BODY SIZE DIMENSIONS INCLUDING MOLD MISMATCH.</div><div>6. DIMENSION DOES NOT INCLUDE DAM BAR PROTRUSION. PROTRUSIONS SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED 0.35. MINIMUM SPACE BETWEEN PROTRUSION AND AN ADJACENT LEAD SHALL BE 0.07 MM.</div><div>7. DIMENSIONS ARE DETERMINED AT THE SEATING PLANE, DATUM A.</div></div>				
TITLE: <div>100 LEAD LQFP</div> 14 X 14, 0.5 PITCH, 1.4 THICK			CASE NUMBER: 983–02	
			STANDARD: NON–JEDEC	
			PACKAGE CODE: 8264	SHEET: 3

Figure 40. 100 LQFP package mechanical drawing (3 of 3)



## 5 Ordering information

Figure 45. Commercial product code structure



<sup>1</sup> 208 MAPBGA available only as development package for Nexus2+

## 6 Document revision history

Table 50 summarizes revisions to this document.

Table 50. Revision history

Revision	Date	Description of Changes
1	04-Apr-2008	Initial release.

Table 50. Revision history (continued)

Revision	Date	Description of Changes
2	06-Mar-2009	<p>Made minor editing and formatting changes to improve readability</p> <p>Harmonized oscillator naming throughout document</p> <p>Features:</p> <ul style="list-style-type: none"> <li>—Replaced 32 KB with 48 KB as max SRAM size</li> <li>—Updated description of INTC</li> <li>—Changed max number of GPIO pins from 121 to 123</li> </ul> <p>Updated <a href="#">Section 1.2, Description</a></p> <p>Updated <a href="#">Table 2</a></p> <p>Added <a href="#">Section 2, Block diagram</a></p> <p><a href="#">Section 3, Package pinouts and signal descriptions</a>: Removed signal descriptions (these are found in the device reference manual)</p> <p>Updated <a href="#">Figure 5</a>:</p> <ul style="list-style-type: none"> <li>—Replaced VPP with VSS_HV on pin 18</li> <li>—Added MA[1] as AF3 for PC[10] (pin 28)</li> <li>—Added MA[0] as AF2 for PC[3] (pin 116)</li> <li>—Changed description for pin 120 to PH[10] / GPIO[122] / TMS</li> <li>—Changed description for pin 127 to PH[9] / GPIO[121] / TCK</li> <li>—Replaced NMI[0] with NMI on pin 11</li> </ul> <p>Updated <a href="#">Figure 4</a>:</p> <ul style="list-style-type: none"> <li>—Replaced VPP with VSS_HV on pin 14</li> <li>—Added MA[1] as AF3 for PC[10] (pin 22)</li> <li>—Added MA[0] as AF2 for PC[3] (pin 77)</li> <li>—Changed description for pin 81 to PH[10] / GPIO[122] / TMS</li> <li>—Changed description for pin 88 to PH[9] / GPIO[121] / TCK</li> <li>—Removed E1UC[19] from pin 76</li> <li>—Replaced [11] with WKUP[11] for PB[3] (pin 1)</li> <li>—Replaced NMI[0] with NMI on pin 7</li> </ul> <p>Updated <a href="#">Figure 6</a>:</p> <ul style="list-style-type: none"> <li>—Changed description for ball B8 from TCK to PH[9]</li> <li>—Changed description for ball B9 from TMS to PH[10]</li> <li>—Updated descriptions for balls R9 and T9</li> </ul> <p>Added <a href="#">Section 3.10, Parameter classification</a> and tagged parameters in tables where appropriate</p> <p>Added <a href="#">Section 3.11, NVUSRO register</a></p> <p>Updated <a href="#">Table 12</a></p> <p><a href="#">Section 3.13, Recommended operating conditions</a>: Added note on RAM data retention to end of section</p> <p>Updated <a href="#">Table 13</a> and <a href="#">Table 14</a></p> <p>Added <a href="#">Section 3.14.1, Package thermal characteristics</a></p> <p>Updated <a href="#">Section 3.14.2, Power considerations</a></p> <p>Updated <a href="#">Figure 7</a></p>

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